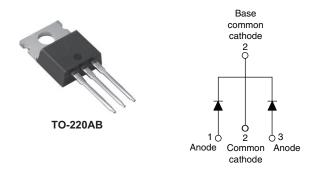


## VS-63CTQ100GPbF, VS-63CTQ100G-N3

**Vishay Semiconductors** 

### Schottky Rectifier, 2 x 30 A



PRODUCT SUMMARY				
Package	TO-220AB			
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>R</sub>	100 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>RM</sub> max.	20 mA at 125 °C			
T <sub>J</sub> max.	175 °C			
Diode variation	Common cathode			
E <sub>AS</sub>	11.25 mJ			

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



RoHS

- Guard ring for enhanced ruggedness and long
  term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform (per device)	60	А		
V <sub>RRM</sub>		100	V		
I <sub>FRM</sub>	$T_{\rm C} = 139 \ ^{\circ}{\rm C}$ (per leg)	60	А		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1500	A		
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.69	V		
TJ	Range	- 65 to 175	°C		

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-63CTQ100GPbF	VS-63CTQ100G-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	100	100	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	100	v		

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	TEST CONDITIONS		UNITS			
Maximum average	per leg			50 % dutu quale et T 120 °C restangular waveform		50.0/ duty evole at T 120.00 restangular waveform		30	
forward current	per device	'F(AV)	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 139 °C, rectangular waveform		60				
Peak repetitive forward current per leg		I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, $T_C$ = 140 °C		60	А			
Maximum peak one cycle non-repetitive surge current per leg			5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	1500				
		IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	300				
Non-repetitive avalanche energy per leg $E_{AS}$ $T_J = 25 \text{ °C}, I_{AS} = 0.75 \text{ A}, L = 40 \text{ mH}$		11.25	mJ						
Repetitive avalanche current per leg I <sub>AR</sub>		I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by $T_J$ maxim		0.75	А			

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		30 A	т ос «о	0.78	0.82	V
Maximum forward valtage drep	V <sub>FM</sub> <sup>(1)</sup>	60 A	T <sub>J</sub> = 25 °C	0.94	1.0	
Maximum forward voltage drop	VFM (''	30 A	T 105 %O	0.64	0.69	
		60 A	T <sub>J</sub> = 125 °C	0.78	0.83	
Maximum instantaneous reverse current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated V <sub>B</sub>	0.02	0.3	mA
		T <sub>J</sub> = 125 °C	VR - naleu VR	11	20	I IIA
Maximum junction capacitance	CT	$V_{\text{R}}$ = 5 $V_{\text{DC}}$ (test signal range 100 kHz to 1 MHz) 25 °C		11	00	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8	.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10	000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C	
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.2	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0/11	
Approximate weight			2	g	
Approximate weight			0.07	oz.	
Mounting torgue minimur	ı	Non-lubricated threads	6 (5)	kgf ⋅ cm	
maximur	n	Non-Indicated inteads	12 (10)	(lbf · in)	
Marking device		Case style TO-220AB	63CTC	0100G	



### VS-63CTQ100GPbF, VS-63CTQ100G-N3

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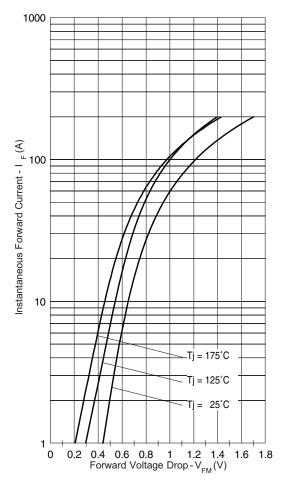


Fig. 1 - Maximum Forward Voltage Drop Characteristics

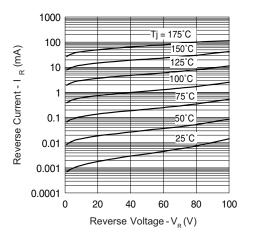


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

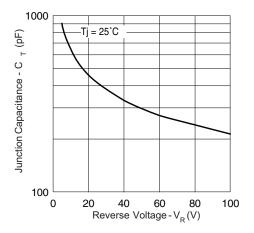
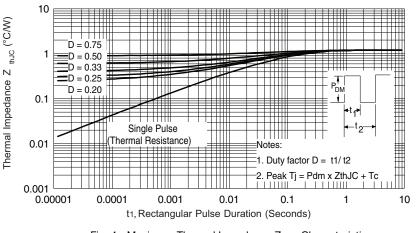
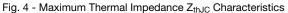
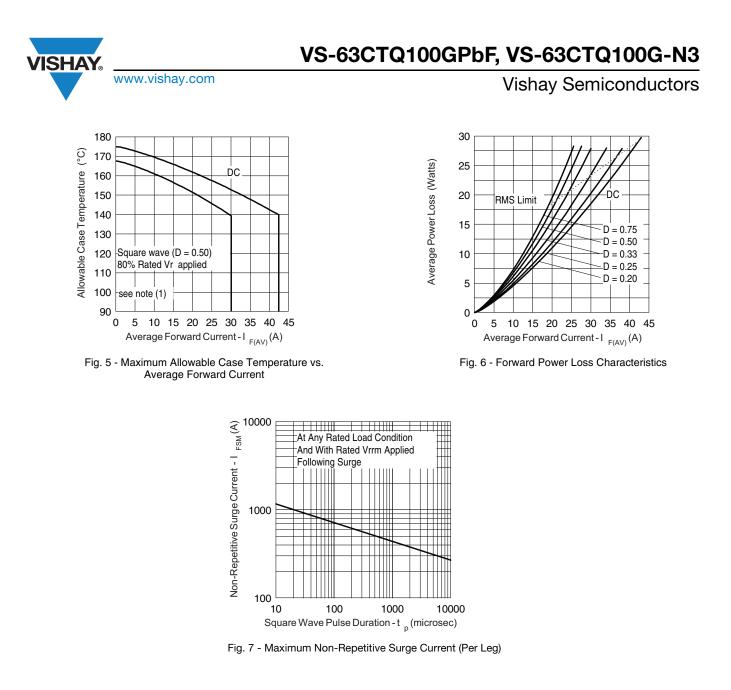


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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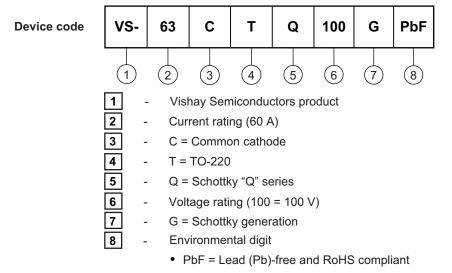
#### Note



## VS-63CTQ100GPbF, VS-63CTQ100G-N3

### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**



• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N      QUANTITY PER T/R      MINIMUM ORDER QUANTITY      PACKAGING DESCRIPTION					
VS-63CTQ100GPbF	50	1000	Antistatic plastic tube		
VS-63CTQ100G-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95222				
	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		



**Vishay Semiconductors** 

**TO-220AB** 

#### **DIMENSIONS** in millimeters and inches





.ead	assignments

**Diodes** 

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIMETERS INCHES		HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- <sup>(3)</sup> Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left( 4\right) }$  Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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